LS285

TELEPHONE SPEECH CIRCUITS

- 2/4 WIRE INTERFACE
- OPERATES DOWN TO 4 mA
- 3.5 Vpp DYNAMIC IN SENDING AT 25 mA

SGS-THOMSON MICROELECTRONICS

DESCRIPTION

The LS285 is monolithic integrated circuits for replacement of the hybrid circuit (2-4 wire interface) in conventional telephones interfacing the two transducers to the line and providing a controlled amount of sidetone.

The same type of transducer can be used for both transmitter and receiver, usually a 350 Ω dynamic type.

By sensing the line current, LS285 adjusts the gain in both directions to compensate for line attenuation.

Output impedance can be matched to the line. independent of transducer impedance.

The LS285 is packaged in a 14 lead dual in-line plastic package.





LS285

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
VL	Line Voltage (3 ms pulse duration)	22	V
1	Forward Current	120	mA
IL.	Reverse Current	- 150	mA
Ptot	Total Power Dissipation at Tamb = 70 °C	1	W
Tstg	Storage and Junction Temperature	- 55 to 150	°C
Тор	Operating Temperature	- 40 to 70	°C

THERMAL DATA

Rth i-amb Thermal Resistance Junction-ambient	Max	80	°C/W
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DESCRIPTION

The LS285 is based on a bridge configuration.

They contain a regulator block, a sending amplifier and a receiver amplifier.

The regulator monitors the line current and adjusts the amplifier gain to compensate for the line length. It provides DC characteristics in line with CEPT standards.

The transmit/receiver amplifiers are connected to the line via an external bridge to provide sidetone attenuation.

The line current compensation ensures that when the subscriber is talking, the signal delivered to the line is increased in according to the line lenght. When he is hearing, the signal level on the receiver capsule is constant.

The amplifiers can also be matched to different transducers simply by varying external components. Gain variation over the operating temperature range is less than ± 1 dB.

Figure 1 : Test Circuit.

The impedance to the line can be adjusted ; without any change in circuit parameters ; by changing an external resistor (6.8 K Ω at pin 2).

BASIC CIRCUIT CONFIGURATION.





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Figure 2 : Sending Gain.



Figure 4 : Sidetone.



Figure 3 : Receiving Gain.







ELECTRICAL CHARACTERISTIC (refer to the test circuit, $T_{amb} = 25$ °C, f = 300 Hz to 3400 Hz, S1, S2 in "a" unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	Fig.
VL	Line Voltage	- 15 °C < T_{amb} < + 45 °C I_L = 80 mA I_L = 20 mA I_L = 10 mA	9.5 4.8 3.6		11.5 5.8 1.6	V	1
Gs	Sending Gain		48.5 47.4 42.7 42.0		52.5 51.5 46.1 45.3	dB	2
Gs	Sending Gain Variation vs. Temp.	$-15 \text{ °C} < T_{amb} < +45 \text{ °C}$		0.8		dB	2
	Sending Gain Flatness	I _L = 10 to 80 mA f _{ref} = 1 KHz S1. S2 in (b)		- 0.5	+ 0.5	dB	2
	Sending Distortion	$I_{L} = 10$ to 15 mA ; $V_{so} = 0.7 V_{p}$			2	%	
		$I_L = 16 \text{ to } 24 \text{ mA}$; $V_{so} = 1.3 \text{ V}_p$			2	%	2
		$I_{L} = 25 \text{ to } 80 \text{ mA}$; $V_{so} = 1.7 \text{ V}_{p}$			10	%	
	Sending Noise	$V_{MI} = 0 V$ $I_{L} = 60 mA$		- 73		dBmp	2
	Microphone Amplifier Impedance (pin 9-10)			95		Ω	1
	Max Sending Output (°)	$I_{L} = 10 \text{ to } 80 \text{ mA}$ $V_{MI} = 1 \text{ V}$			3	Vp	2
GR	Receiving Gain	$ f = 1 \ \text{KHz} \\ I_L = 15 \ \text{mA} \ ; V_{\text{RI}} = 0.8 \ \text{V}_{\text{RMS}} \\ I_L = 30 \ \text{mA} \ ; V_{\text{RI}} = 1.0 \ \text{V}_{\text{RMS}} \\ I_L = 60 \ \text{mA} \ ; V_{\text{RI}} = 1.8 \ \text{V}_{\text{RMS}} \\ I_L = 80 \ \text{mA} \ ; V_{\text{RI}} = 10 \ \text{V}_{\text{RMS}} $	- 13.3 - 13.5 - 18 - 19		- 9.6 - 10.5 - 14.9 - 16	dB	3
ΔG _R	Receiving Gain Variation vs. Temperature	- 15 °C < Tamb < + 45 °C		0.25		dB	3
	Receiving Gain Flatness	$f_{ref} = 1 \text{ KHz} I_L = 10 \text{ to } 80 \text{ mA}$ S1, S2 in (b)	- 0.5		+ 0.5	dB	3
	Receiving Distortion	$I_L = 10 \text{ to } 15 \text{ mA}$ $V_{RO} = 300 \text{ mV}_p$			2	0/	
		$I_L = 15 \text{ to } 80 \text{ mA}$ $V_{RO} = 500 \text{ mV}_p$			2	%	5
	Receiving Amplifier Output Impedance (pin 1-4)			110		Ω	1
	Receiving Noise	V _{RI} = 0 V I _L = 60 mA psophometric		80		μV	3
	Max receiving Output Current	l _L = 80 mA V _{BI} = 10 V			3.6	mAp	3

(*) This output is limited to allow for input overvoltages.



ELECTRICAL CHARACTERISTIC (continued)

Symbol	Parameter	Test	Test Conditions		Тур.	Max.	Unit	Fig.
	Sidetone	f = 1 KHz	I _L = 20 mA		7		dB	4
			l_ = 80 mA		0		dB	4
	Return Loss	S3 in (a)	S3 in (a)		14		dB	5
		S3 in (b)			14		dB	5

(*) This output is limited to allow for input overvoltages.







APPLICATION INFORMATION

The following table shows the recommended values for the typical application circuit of fig. 6. Different values can be used and notes are added in order to help designer.

Component	Recommended Value	Purpose	Note				
R1	75 Ω	Bridge Resistors	The ratio R2/R1 fixes the amount of the signal				
R2	536 Ω		delivered to the line. (see fig. 7)				
R3	16.2 ΚΩ	Bias Resistor	Changing R3 value it is possible to shift the gain characteristics. The value can be chosen from 15 K Ω to 20 K Ω . The recommended value assures the maximum swing (see fig. 9).				
R4	2.05 KΩ	Balance Network	In order to optimize the sidetone it is possible				
R 5	9.09 KΩ		to change R4 and R5 values. In any case : $\frac{Z_B}{Z_L} = \frac{R2}{R1}$ where $Z_B = R4 + R5//C4$.				
R6 and R6	250 Ω	Microphone Impedance Matching	R6 and R6' must be equal ; 250 Ω is a typical value for dynamic capsules. Furthermore, they determine a sending gain variation according to : $\Delta G_s = 20 \log \frac{Rx}{850 \Omega}$ where Rx = R6 + R6' + R _{mike} . The trend of ΔG_s as a function of Rx value is shown in fig. 8.				
R7 and R7'	100 Ω	Receive Impedance Matching	R7 and R7' must be equal ; 100 Ω is a typical value for dynamic capsules.				
C1	10 µF	AC Loop Opening	Ensures a high regulator impedance for AC signals (= 20 K Ω). This capacitor should not be higher than 10 μ F in order to have a short response time of the system.				
C2	22 nF	Matching to a Capacitive Line	C2 changes with the characteristics of the transmission line.				
C3	82 nF	High Frequency Roll-off	C3 determines the high frequency response of the circuit. it also acts as RF bypass.				
C4	22 nF	Balance Network	See Note for R4 and R5.				
C5	1 μF	DC decoupling for Receiving Input					
C6 and C7	1000 pF	RF Bypass					
C8	22 nF	Filter Capacitor					



Figure 7 : Receiving Gain Variation vs. R1 Value (with fixed R1/R2 ratio).







Figure 8 : Sending Gain Variation vs. Rx Value (see note for R6 and R6').

